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2014年1月

FCP13N60N / FCPF13N60NT

N 沟道 SupreMOS[®] MOSFET 600 V, 13 A, 258 m Ω

特性

- $R_{DS(on)}$ = 220 $m\Omega$ (Typ.) @ V_{GS} = 10 V, I_D = 6.5 A
- 超低栅极电荷 (典型值 Q_q = 30.4 nC)
- 低有效输出电容 (典型值 Coss(eff.)= 145 pF)
- 100% 经过雪崩测试
- 符合 RoHS 标准

应用

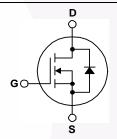
- LCD/LED/PDP 电视
- 照明
- 太阳能逆变器
- AC-DC 电源

说明

SupreMOS[®] MOSFET 是飞兆半导体的下一代高压超级结(SJ)技术,该技术采用区别于传统 SJ MOSFET 产品的深沟槽填充工艺。这项先进技术和精密的工艺控制提供了最低的 Rsp onresistance(导通电阻规格),卓越的开关性能和耐用性。SupreMOS MOSFET 技术适用于高频开关电源转换器应用,如功率因数校正 (PFC)、服务器/电信电源、平板电视电源、ATX电源及工业电源应用。







MOSFET 最大额定值针对 T_C = 25℃ 除非另有说明。

符号		参数	FCP13N60N	FCPF13N60NT	单位
V_{DSS}	漏极一源极电压		6	V	
V_{GSS}	栅极一源极电压		±	V	
	足机中次	- 连续 (T _C = 25°C)	13	13*	Α
		- 连续 (T _C = 100°C)	8.2	8.2*	A
I _{DM}	漏极电流 - 脉冲 (注 1)		39	39	Α
E _{AS}	单脉冲雪崩能量	2	35	mJ	
I _{AR}	雪崩电流 (注 1)		4.3		Α
E _{AR}	重复雪崩能量	1.16		mJ	
dv/dt	MOSFET dv/dt		100		V/ns
av/ai	二极管恢复 dv/dt 峰值	(注3)	20		V/ns
D	T-L #T	(T _C = 25°C)	116	33.8	W
P_{D}	功耗	- 超过 25°C 时降额	0.93	0.27	W/°C
T _J , T _{STG}	工作和存储温度范围	-55 至	+150	°C	
T_L	用于焊接的最大引脚温度,距离	图外壳 1/8",持续 5 秒	3	00	°C

*漏极电流受限于最大结温。

热性能

符号	参数	FCP13N60N	FCPF13N60NT	单位
$R_{\theta JC}$	热阻,结至外壳,最大值	1.07	3.7	°C/W
$R_{\theta JA}$	结至环境热阻最大值	62.5	62.5	C/VV

封装标识与定购信息

器件编号	顶标	封装	包装方法	卷尺寸	带宽	数量
FCP13N60N	FCP13N60N	TO-220	塑料管	不适用	不适用	50 单元
FCPF13N60NT	FCPF13N60NT	TO-220F	塑料管	不适用	不适用	50 单元

电气特性 T_C = 25℃ 除非另有说明。

符号	参数	测试条件	最小值	典型值	最大值	单位
关断特性						
BV _{DSS}	漏极一源极击穿电压	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}, T_C = 25^{\circ}\text{C}$	600	-	-	V
ΔBV _{DSS} / ΔT _J	击穿电压温度系数	I _D = 1 mA,参考 25°C	-	0.73	-	V/°C
I	零栅极电压漏极电流	V _{DS} = 480 V, V _{GS} = 0 V	-	-	10	
IDSS	令	$V_{DS} = 480 \text{ V}, V_{GS} = 0 \text{ V}, T_{C} = 125 ^{\circ}\text{C}$	1	-	100	μΑ
I _{GSS}	栅极 - 体漏电流	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	ı	-	±100	nA

导通特性

V _{GS(th)}	栅极阈值电压	$V_{GS} = V_{DS}, I_{D} = 250 \mu\text{A}$	2.0	-	4.0	V
R _{DS(on)}	漏极至源极静态导通电阻	$V_{GS} = 10 \text{ V}, I_D = 6.5 \text{ A}$	-	0.220	0.258	Ω
9 _{FS}	正向跨导	$V_{DS} = 40 \text{ V}, I_{D} = 6.5 \text{ A}$	-	16.3	-	S

动态特性

C _{iss}	输入电容	V 400 V V 0 V	-	1325	1765	pF
C _{oss}	输出电容	V _{DS} = 100 V, V _{GS} = 0 V, f = 1 MHz		50	65	pF
C _{rss}	反向传输电容			3	5	pF
C _{oss}	输出电容	$V_{DS} = 380 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-	30		pF
C _{oss(eff.)}	有效输出电容	$V_{DS} = 0 V \cong 480 V, V_{GS} = 0 V$	-	145		pF
$Q_{g(tot)}$	10 V 的栅极电荷总量	$V_{DS} = 380 \text{ V}, I_{D} = 6.5 \text{ A},$	-	30.4	39.5	nC
Q_{gs}	栅极 - 源极栅极电荷	V _{GS} = 10 V	-	6.0		nC
Q_{gd}	栅极 - 漏极 " 密勒 " 电荷	(说明 4)	-	9.5		nC
ESR	等效串联电阻 (G-S)	f = 1 MHz	-	2.8		Ω

开关特性

t _{d(on)}	导通延迟时间		-	14.5	39	ns
t _r	开通上升时间	$V_{DD} = 380 \text{ V}, I_D = 6.5 \text{ A},$	-	10.6	31.2	ns
t _{d(off)}	关断延迟时间	$V_{GS} = 10 \text{ V}, R_{G} = 4.7 \Omega$	-	45	100	ns
t _f	关断下降时间	(说明 4)	/ · -	9.8	29.6	ns

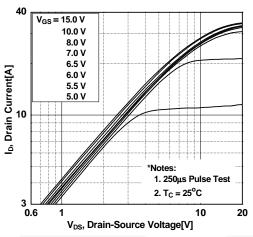
漏极 - 源极二极管特性

I _S	漏极 - 源极二极管最大正向连续电流		-	-	13*	Α
I_{SM}	漏极 - 源极二极管最大正向脉冲电流		-	-	39	Α
V_{SD}	漏极 - 源极二极管正向电压	$V_{GS} = 0 \text{ V}, I_{SD} = 6.5 \text{ A}$	-	-	1.2	V
t _{rr}	反向恢复时间	$V_{GS} = 0 \text{ V}, I_{SD} = 6.5 \text{ A},$	-	287	-	ns
Q _{rr}	反向恢复电荷	$dI_F/dt = 100 A/\mu s$	-	3.5	//	μС

- 1. 重复额定值:脉冲宽度受限于最大结温。
- 2. $I_{AS} = 4.3 \text{ A}$, $R_G = 25 \Omega$, 启动 $T_J = 25 ^{\circ}\text{C}$ 。
- 3. $I_{SD} \le 13$ A, $di/dt \le 200$ A/ μ s, $V_{DD} \le BV_{DSS}$,启动 $T_J = 25$ °C。 4. 本质上独立于工作温度的典型特性。

典型性能特征

图 1. 导通区域特性



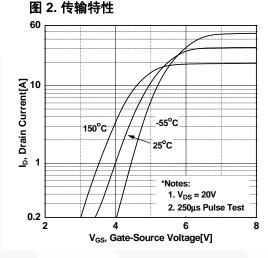


图 3. 导通电阻变化与漏极电流和栅极电压

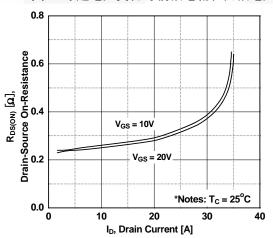


图 4. 体二极管正向电压变化与源极电流和温度

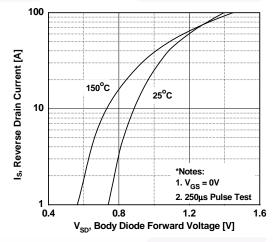


图 5. 电容特性

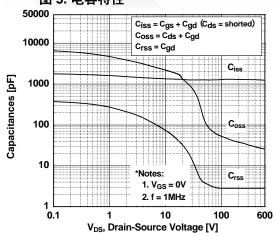
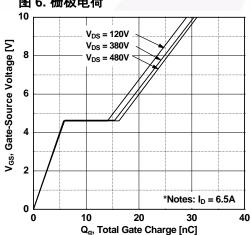


图 6. 栅极电荷



典型性能特征 (接上页)

图 7. 击穿电压变化与温度

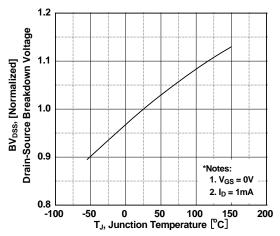


图 8. 导通电阻变化与温度

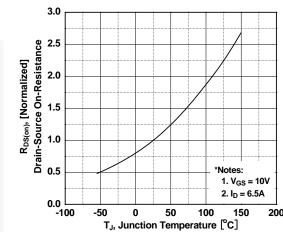


图 9. 最大安全工作区 - FCP13N60N

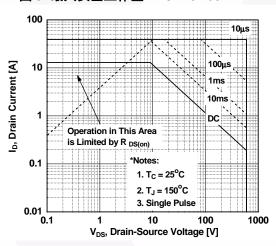


图 10. 最大安全操作区 - FCPF13N60NT

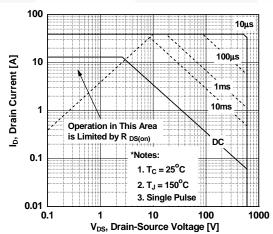
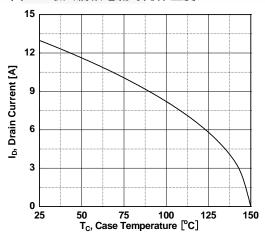
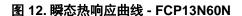


图 11. 最大漏极电流与壳体温度



典型性能特征 (接上页)



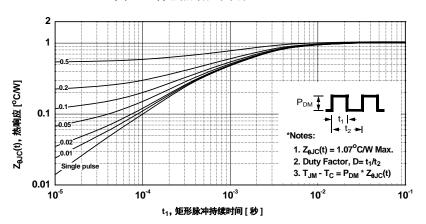
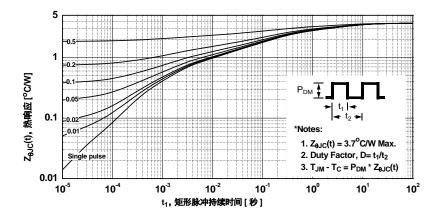


图 13. 瞬态热响应曲线 - FCPF13N60NT



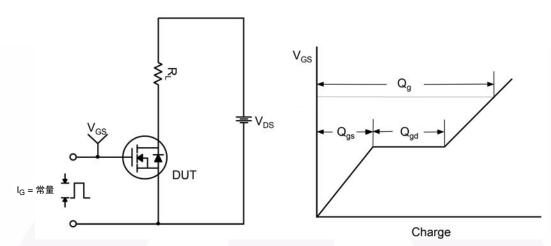


图 14. 栅极电荷测试电路与波形

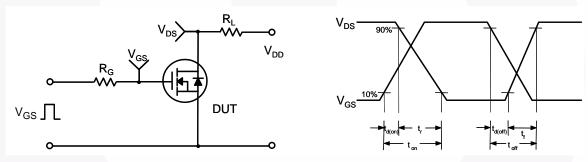


图 15. 阻性开关测试电路与波形

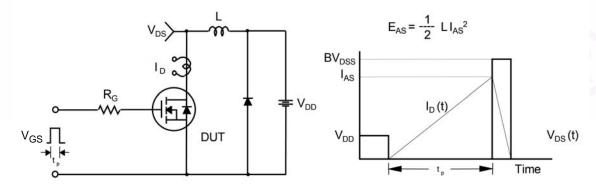


图 16. 非箝位感性开关测试电路与波形

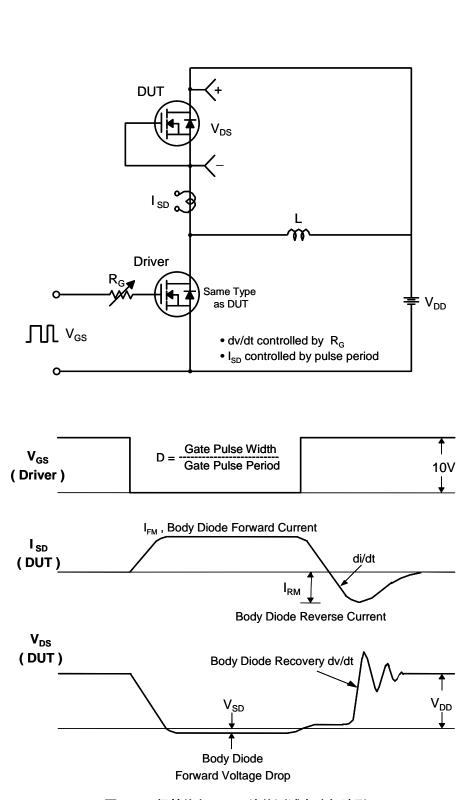


图 17. 二极管恢复 dv/dt 峰值测试电路与波形

机械尺寸

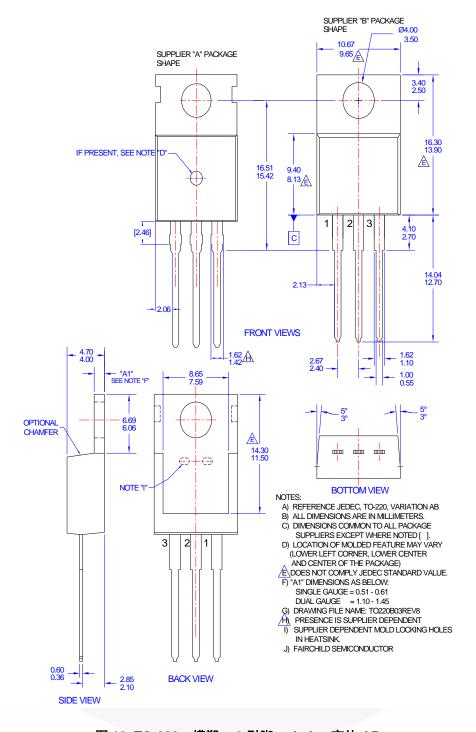


图 18. TO-220, 模塑, 3 引脚, Jedec 变体 AB

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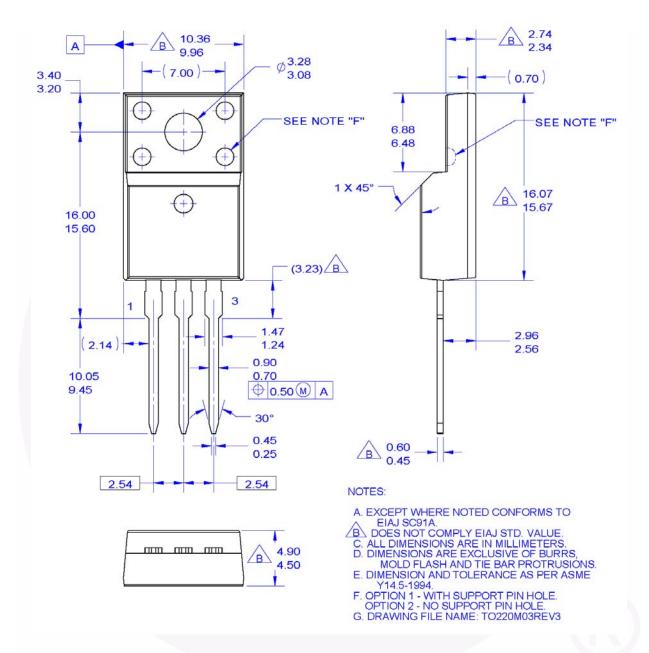


图 19. TO220, 模塑, 3 引脚,全封装, EIAJ SC91,直引脚

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